

6MBI100VX-120-50

IGBT Modules

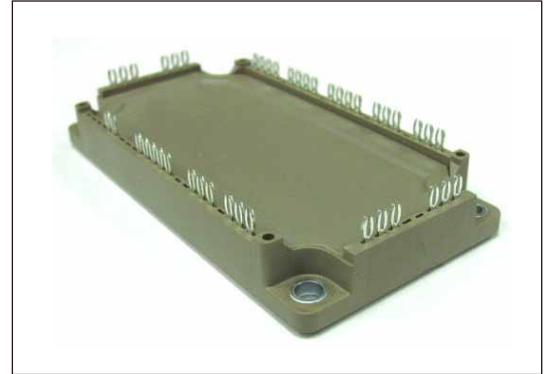
IGBT MODULE (V series) 1200V / 100A / 6 in one package

■ Features

- Compact Package
- P.C.Board Mount
- Low $V_{CE(sat)}$

■ Applications

- Inverter for Motor Drive
- AC and DC Servo Drive Amplifier
- Uninterruptible Power Supply
- Industrial machines, such as welding machines



■ Maximum Ratings and Characteristics

● Absolute Maximum Ratings (at $T_c=25^\circ\text{C}$ unless otherwise specified)

Items		Symbols	Conditions	Maximum ratings	Units	
Inverter	Collector-Emitter voltage	V_{CES}		1200	V	
	Gate-Emitter voltage	V_{GES}		± 20	V	
	Collector current	I_c	Continuous	$T_c=100^\circ\text{C}$	100	A
		I_{cp}	1ms	$T_c=80^\circ\text{C}$	200	
		$-I_c$			100	
	$-I_c$ pulse	1ms		200		
	Collector power dissipation	P_c	1 device	520	W	
	Junction temperature	T_j		175	$^\circ\text{C}$	
	Operating junction temperature (under switching conditions)	T_{jop}		150		
	Case temperature	T_c		125		
	Storage temperature	T_{stg}		-40 to +125		
Isolation voltage	between terminal and copper base (*1) between thermistor and others (*2)	V_{iso}	AC : 1min.	2500	VAC	
Screw torque	Mounting (*3)	-	M5	3.5	N m	

Note *1: All terminals should be connected together during the test.

Note *2: Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

Note *3: Recommendable value : 2.5-3.5 Nm (M5)

● Electrical characteristics (at Tj= 25°C unless otherwise specified)

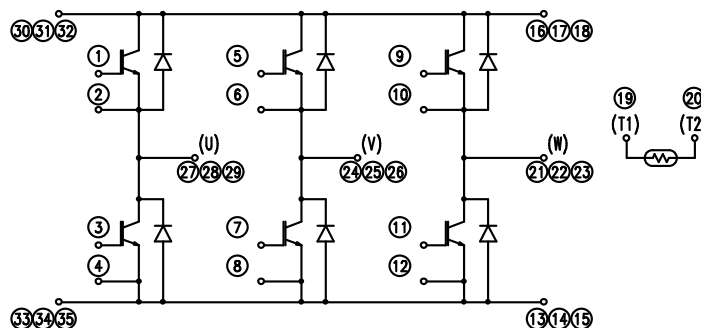
Items	Symbols	Conditions	Characteristics			Units	
			min.	typ.	max.		
Zero gate voltage collector current	I_{CES}	$V_{GE} = 0V, V_{CE} = 1200V$	-	-	1.0	mA	
Gate-Emitter leakage current	I_{GES}	$V_{GE} = 0V, V_{CE} = \pm 20V$	-	-	200	nA	
Gate-Emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = 20V, I_c = 100mA$	6.0	6.5	7.0	V	
Collector-Emitter saturation voltage	$V_{CE(sat)}$ (terminal)	$V_{GE} = 20V$ $I_c = 100A$	Tj=25°C	-	2.25	2.70	V
			Tj=125°C	-	2.55	-	
			Tj=150°C	-	2.60	-	
	$V_{CE(sat)}$ (chip)	$V_{GE} = 15V$ $I_c = 100A$	Tj=25°C	-	1.75	2.20	
			Tj=125°C	-	2.05	-	
			Tj=150°C	-	2.10	-	
Internal gate resistance	$R_g(int)$	-	-	7.5	-	Ω	
Input capacitance	C_{ies}	$V_{CE} = 10V, V_{GE} = 0V, f = 1MHz$	-	9.1	-	nF	
Turn-on time	t_{on}	$V_{CC} = 600V$ $I_c = 100A$ $V_{GE} = +15 / -15V$ $R_G = 1.6\Omega$	-	0.39	1.20	μs	
	t_r		-	0.09	0.60		
	$t_r(i)$		-	0.03	-		
Turn-off time	t_{off}		-	0.53	1.00	μs	
	t_f		-	0.06	0.30		
Forward on voltage	V_F (terminal)	$I_F = 100A$	Tj=25°C	-	2.20	2.65	V
			Tj=125°C	-	2.35	-	
			Tj=150°C	-	2.30	-	
	V_F (chip)	$I_F = 100A$	Tj=25°C	-	1.70	2.15	
			Tj=125°C	-	1.85	-	
			Tj=150°C	-	1.80	-	
Reverse recovery time	t_{rr}	$I_F = 100A$	-	-	0.35	μs	
Thermistor	Resistance	T = 25°C	-	5000	-	Ω	
		T = 100°C	465	495	520		
	B value	B	T = 25 / 50°C	3305	3375	3450	K

● Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	max.	
Thermal resistance (1device)	$R_{th(j-c)}$	Inverter IGBT	-	-	0.29	°C/W
		Inverter FWD	-	-	0.44	
Contact thermal resistance (1device) (*4)	$R_{th(c-f)}$	with Thermal Compound	-	0.05	-	

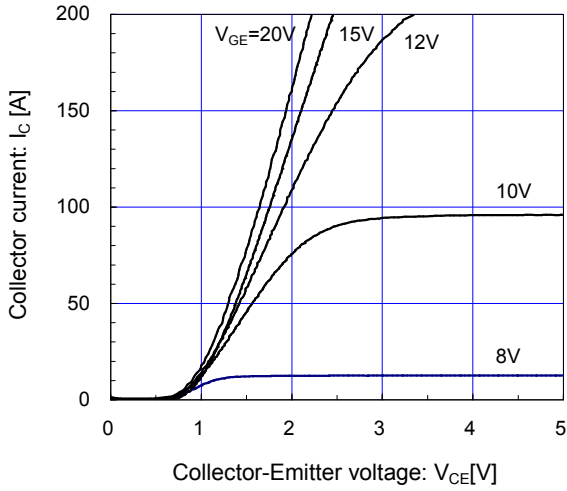
Note *4: This is the value which is defined mounting on the additional cooling fin with thermal compound.

■ Equivalent Circuit Schematic

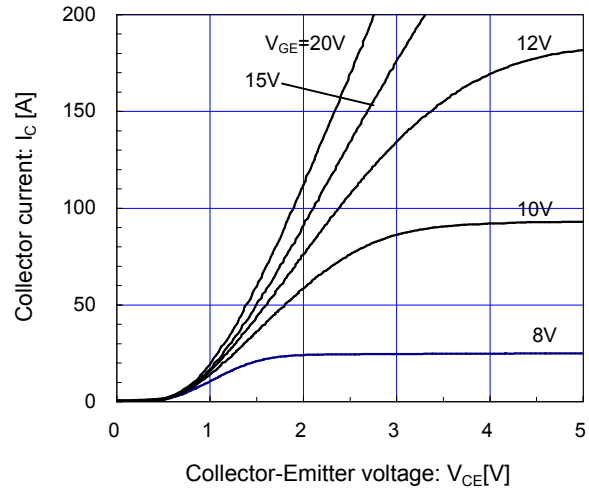


■ Characteristics (Representative)

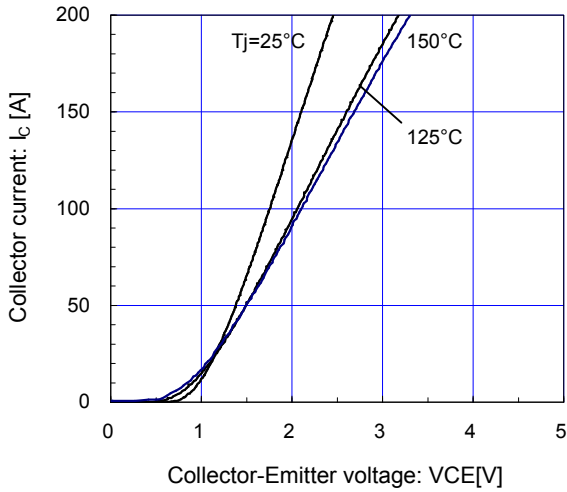
[Inverter]
Collector current vs. Collector-Emmitter voltage (typ.)
Tj= 25°C / chip



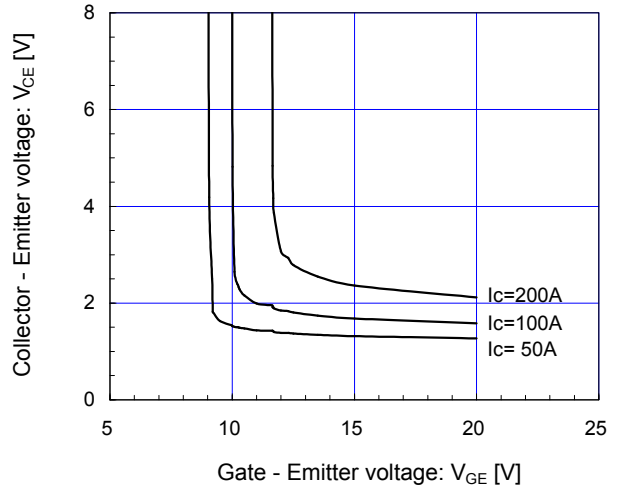
[Inverter]
Collector current vs. Collector-Emmitter voltage (typ.)
Tj= 150°C / chip



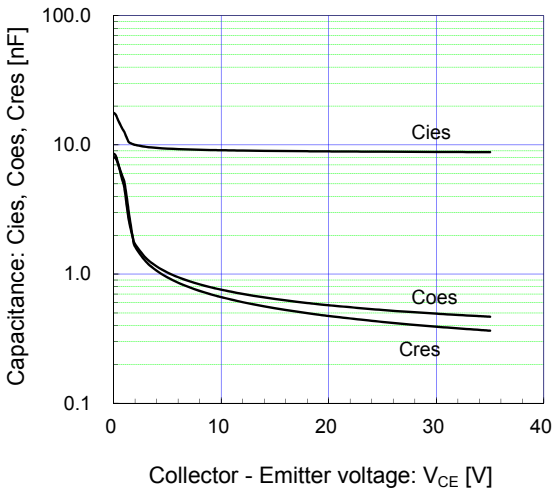
[Inverter]
Collector current vs. Collector-Emmitter voltage (typ.)
VGE=15V / chip



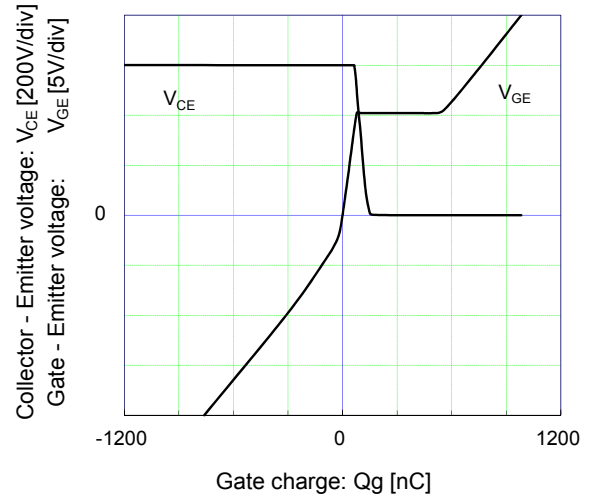
[Inverter]
Collector-Emmitter voltage vs. Gate-Emmitter voltage (typ.)
Tj= 25°C / chip



[Inverter]
Capacitance vs. Collector-Emmitter voltage (typ.)
VGE=0V, f= 1MHz, Tj= 25°C

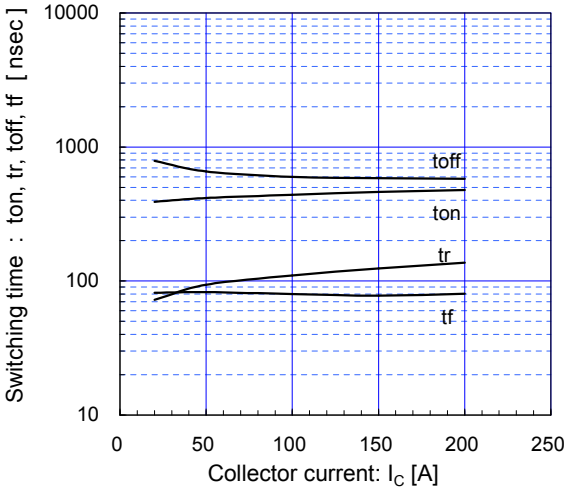


[Inverter]
Dynamic gate charge (typ.)
Vcc=600V, Ic=100A, Tj= 25°C



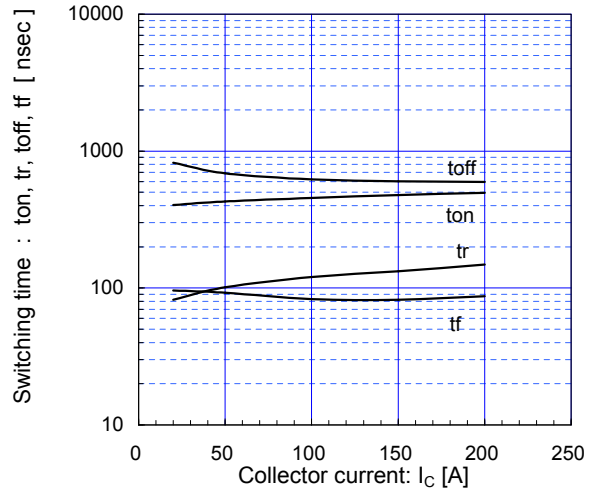
[Inverter]

Switching time vs. Collector current (typ.)
 $V_{cc}=600V, V_{GE}=\pm 15V, R_g=1.6\Omega, T_j=125^\circ C$



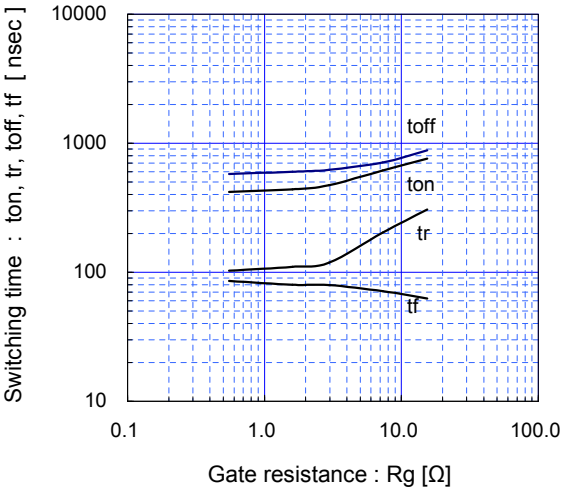
[Inverter]

Switching time vs. Collector current (typ.)
 $V_{cc}=600V, V_{GE}=\pm 15V, R_g=1.6\Omega, T_j=150^\circ C$



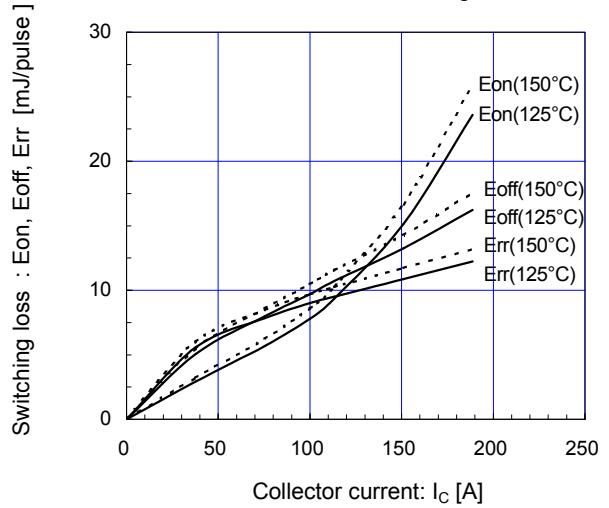
[Inverter]

Switching time vs. gate resistance (typ.)
 $V_{cc}=600V, I_C=100A, V_{GE}=\pm 15V, T_j=125^\circ C$



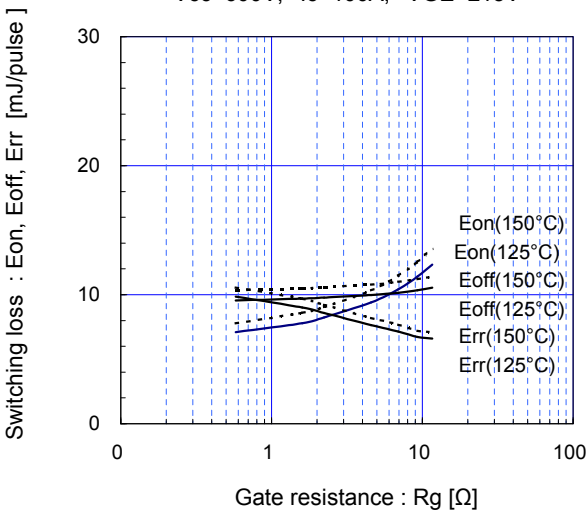
[Inverter]

Switching loss vs. Collector current (typ.)
 $V_{cc}=600V, V_{GE}=\pm 15V, R_g=1.6\Omega$



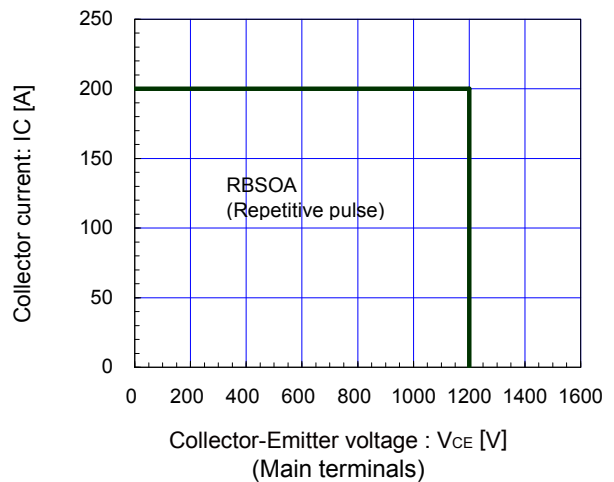
[Inverter]

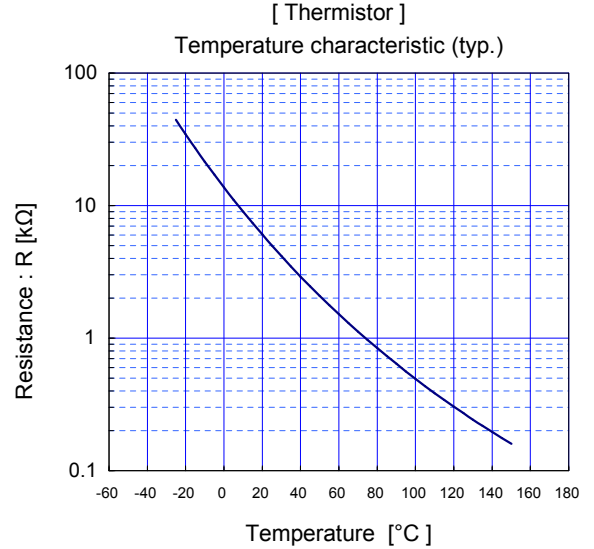
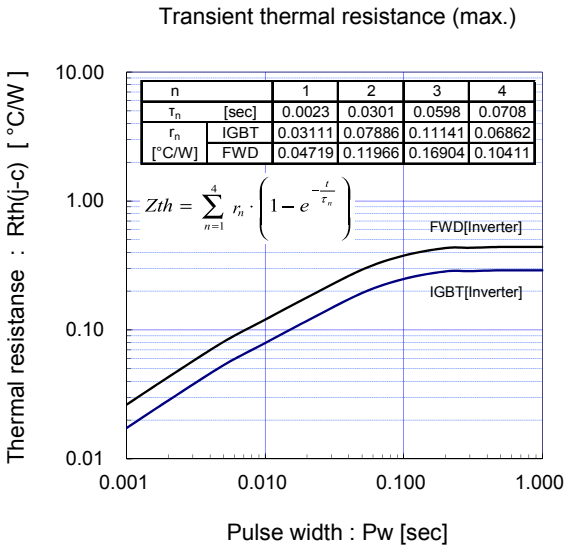
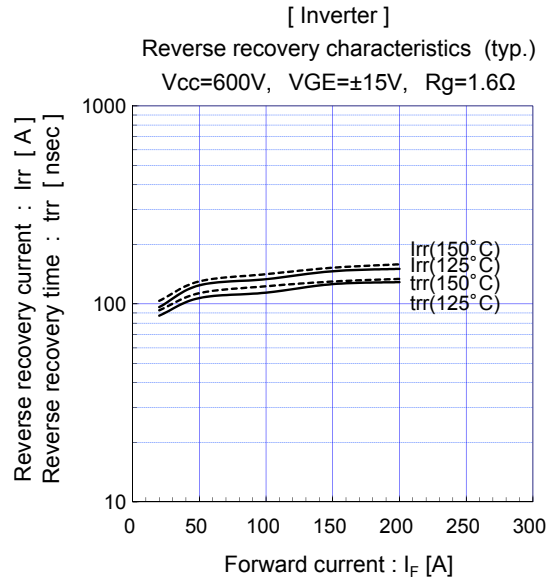
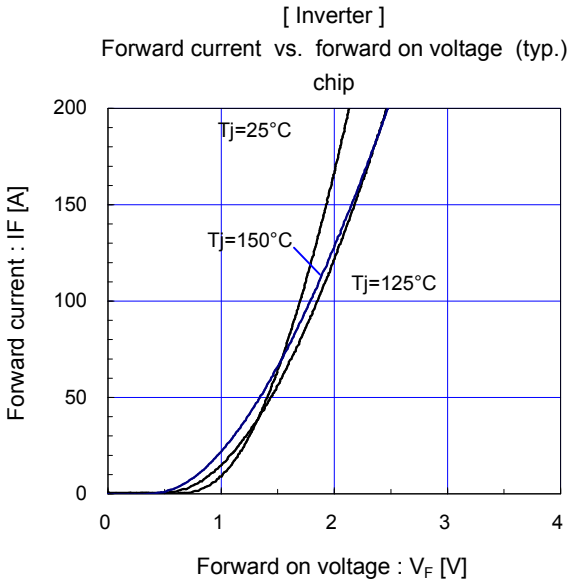
Switching loss vs. gate resistance (typ.)
 $V_{cc}=600V, I_C=100A, V_{GE}=\pm 15V$



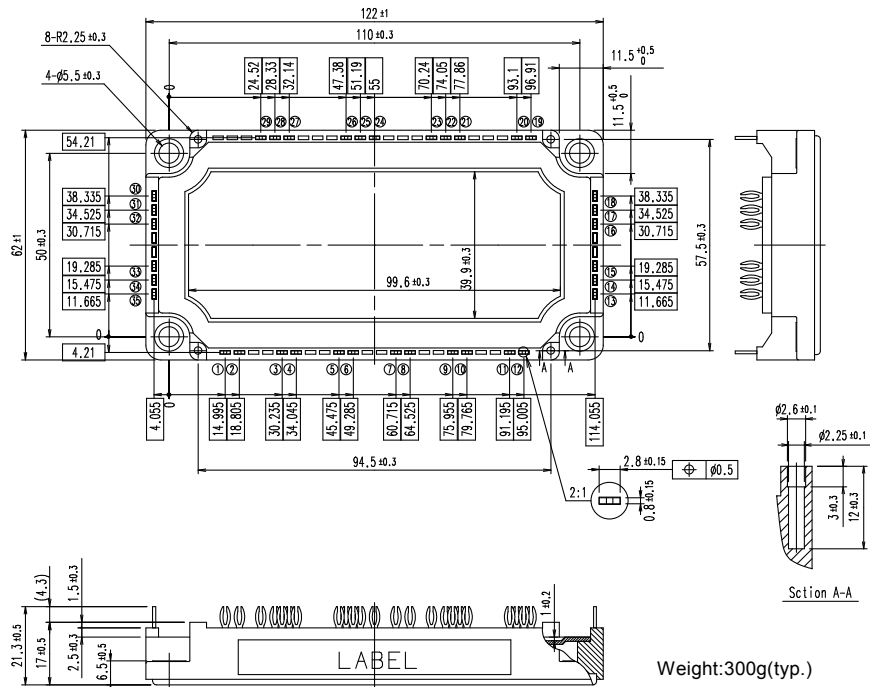
[Inverter]

Reverse bias safe operating area (max.)
 $+V_{GE}=15V, -V_{GE} \leq 15V, R_g \geq 1.6\Omega, T_j=150^\circ C$





■ Outline Drawings, mm



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